

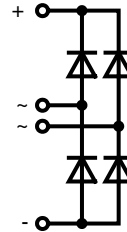
Single Phase Rectifier Bridge

$I_{dAV} = 18 \text{ A}$
 $V_{RRM} = 800-1600 \text{ V}$

Standard and Avalanche Types

V_{RSM} V	V_{BRmin} ① V	V_{RRM} V	Standard Types	Avalanche Types
900		800	VBO 13-08NO2	
1300	1230	1200	VBO 13-12NO2	VBO 13-12AO2
1700	1630	1600	VBO 13-16NO2	VBO 13-16AO2

① For Avalanche Types only



Symbol	Conditions	Maximum Ratings	Features
I_{dAV} ②	$T_C = 85^\circ\text{C}$, module	18 A	<ul style="list-style-type: none"> Avalanche rated parts available Package with DCB ceramic base plate Isolation voltage 3600 V~ Planar passivated chips Low forward voltage drop 1/4" fast-on terminals UL registered E 72873
I_{dAVM}	module	30 A	
P_{RSM}	$T_{VJ} = T_{VJM}$	2.5 kW	
I_{FSM}	$T_{VJ} = 45^\circ\text{C}; V_R = 0$	$t = 10 \text{ ms}$ (50 Hz)	220 A
		$t = 8.3 \text{ ms}$ (60 Hz)	230 A
	$T_{VJ} = T_{VJM}; V_R = 0$	$t = 10 \text{ ms}$ (50 Hz)	180 A
		$t = 8.3 \text{ ms}$ (60 Hz)	190 A
I^2t	$T_{VJ} = 45^\circ\text{C}; V_R = 0$	$t = 10 \text{ ms}$ (50 Hz)	240 A ² s
		$t = 8.3 \text{ ms}$ (60 Hz)	220 A ² s
	$T_{VJ} = T_{VJM}; V_R = 0$	$t = 10 \text{ ms}$ (50 Hz)	160 A ² s
		$t = 8.3 \text{ ms}$ (60 Hz)	150 A ² s
T_{VJ}		-40...+150 °C	Applications <ul style="list-style-type: none"> Supplies for DC power equipment Input rectifiers for PWM inverter Battery DC power supplies Field supply for DC motors
T_{VJM}		150 °C	
T_{stg}		-40...+125 °C	
V_{ISOL}	50/60 Hz, RMS $t = 1 \text{ min}$ $I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3000 V~	Advantages <ul style="list-style-type: none"> Easy to mount with one screw Space and weight savings Improved temperature & power cycling
		3600 V~	
M_d	Mounting torque (M5) (10-32 UNF)	1.5-2 Nm 13-18 lb.in.	Dimensions in mm (1 mm = 0.0394")
Weight	Typ.	15 g	

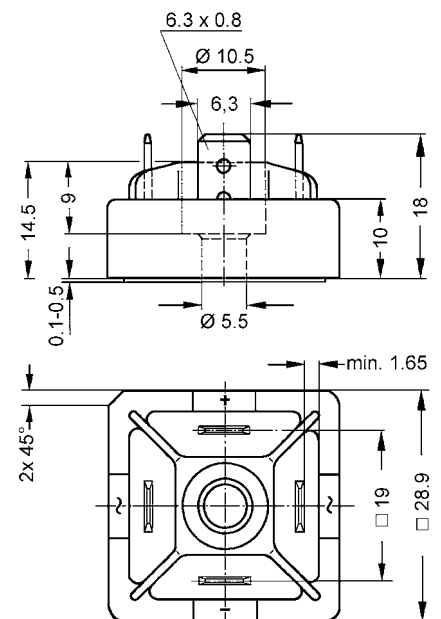
Symbol	Conditions	Characteristic Values
I_R	$V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = T_{VJM}$	0.3 mA
		5.0 mA
V_F	$I_F = 55 \text{ A}$ $T_{VJ} = 25^\circ\text{C}$	1.8 V
V_{TO}	For power-loss calculations only	0.85 V
r_t		17 mΩ
R_{thJC}	per diode; 120° el.	5.60 K/W
	per module	1.40 K/W
R_{thJH}	per diode; 120° el.	6.00 K/W
	per module	1.50 K/W
d_s	Creeping distance on surface	13 mm
d_a	Creepage distance in air ③	9.5 mm
a	Max. allowable acceleration	50 m/s ²

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

② for resistive load at bridge output

③ with isolated fast-on tabs.

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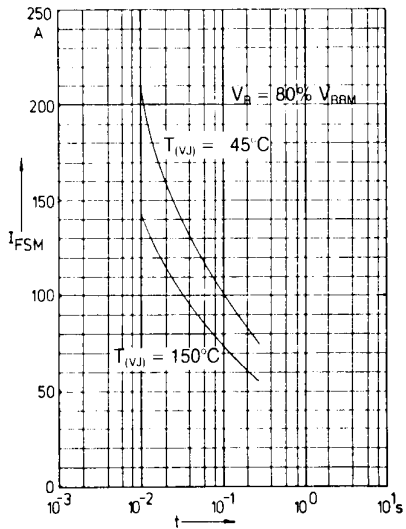


Fig. 1 Surge overload current per diode
 I_{FSM} : Crest value, t : duration

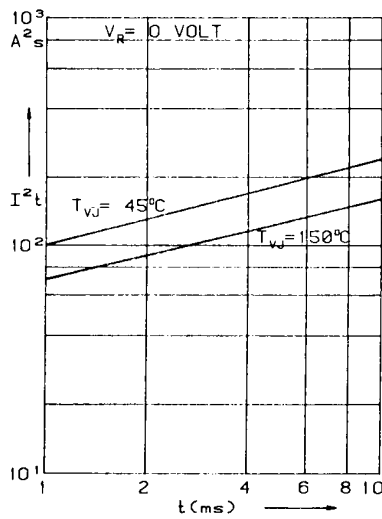


Fig. 2 I^2t versus time (1-10 ms) per diode

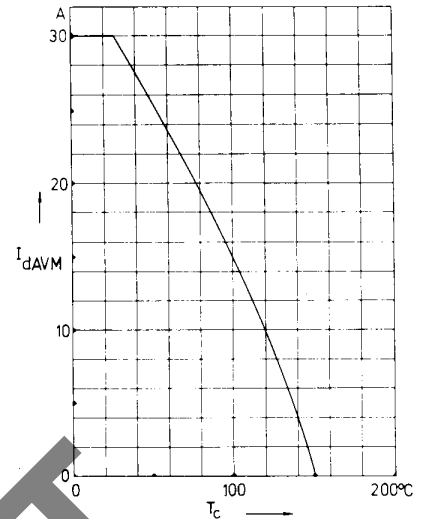


Fig. 3 Max. forward current at case temperature

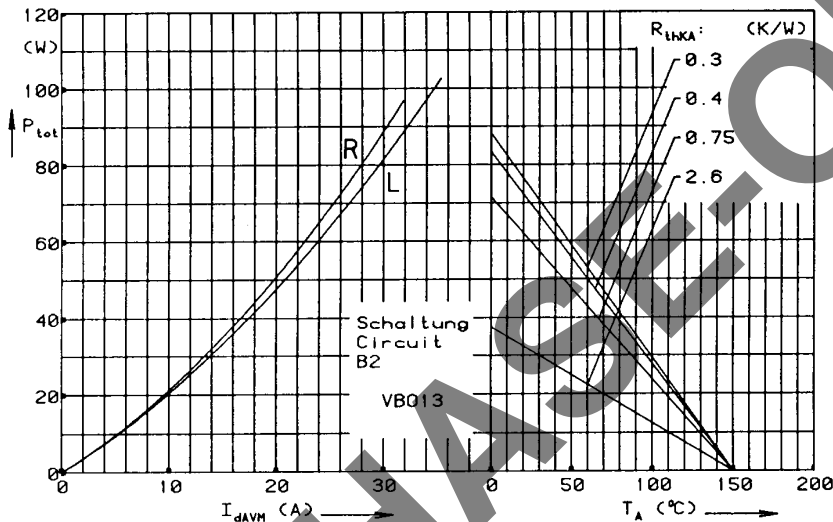


Fig. 4 Power dissipation versus direct output current and ambient temperature

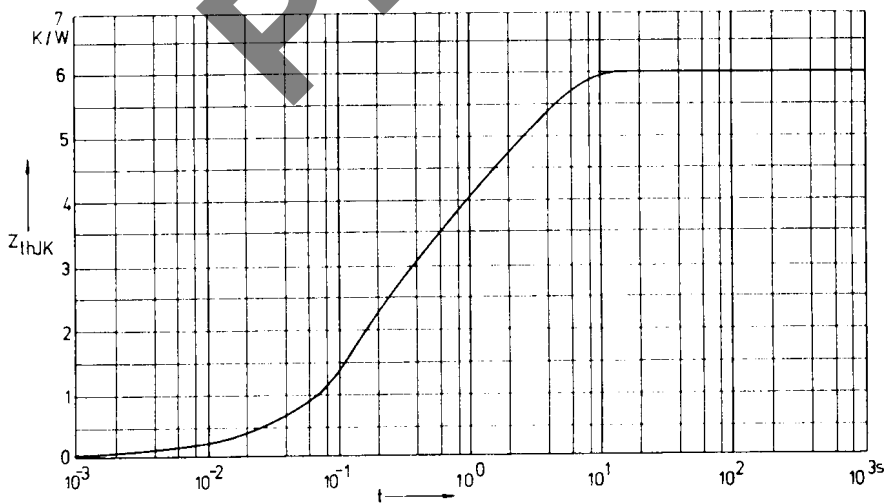


Fig. 5 Transient thermal impedance junction to heatsink per diode

Constants for $Z_{\theta JK}$ calculation:

i	$R_{\theta i}$ (K/W)	t_i (s)
1	0.059	0.00217
2	2.714	0.159
3	3.227	2.34